



Stitch Aware Detailed Placement for Multiple E-Beam Lithography

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Outline

- Introduction
- Previous Work
- Problem Formulation
- Stitch Aware Detailed Placement
- Experimental Results
- Conclusion

Introduction

- Technology Scaling

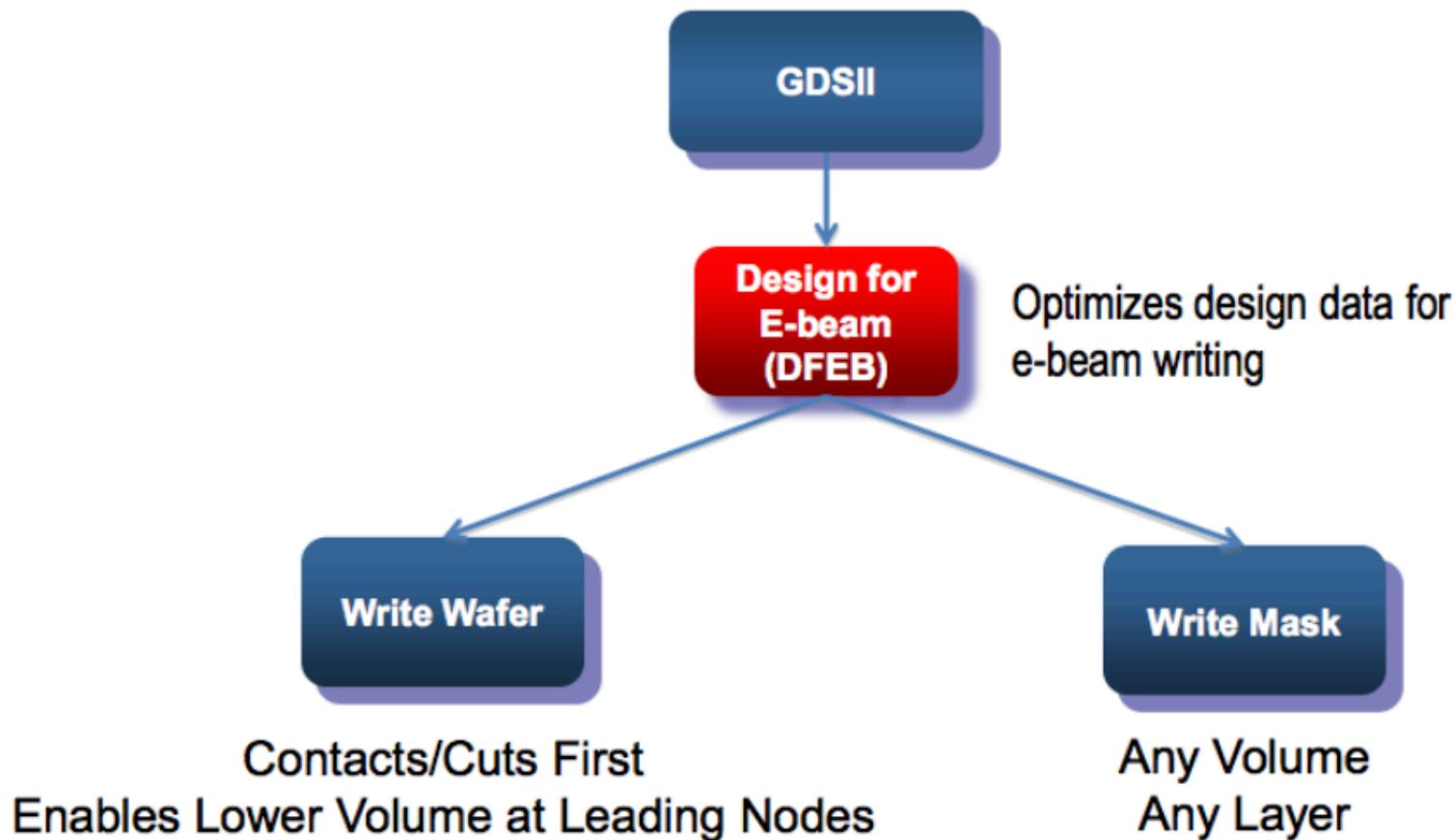
Uni-directional parallel line/space patterning techniques																			
	CD	40	38	36	34	32	30	28	26	24	22	20	18	16	14	12	10	8	6
Exposure tool	Pitch	80	76	72	68	64	60	56	52	48	44	40	36	32	28	24	20	16	12
Immersion	→																		
Immersion	→					19					20								
Immersion	→											2							
Immersion	→												5		1				
EUV	→													18					
EUV	→													4		6			
Immersion	→														3	12			
ArF, EUV, E-beam	→																11		
Nanoimprint	→													13				14	
High NA EUV	→																17		
E-beam	→		7							8				15		16			
E-beam	→		Large features do no phase separate well by DSA											9	10	12			

[Courtesy ITRS]

- Consenses that technique has been used in production
- Published demonstrations from potential deployable equipment show opportunity for production
- Simulations, surface images, or research grade demonstration suggest potential for extendability

E-Beam Lithography

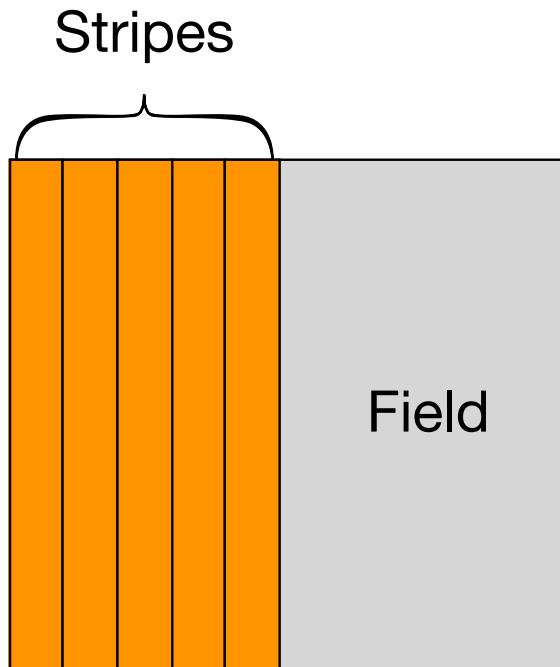
- Direct-write or mask?



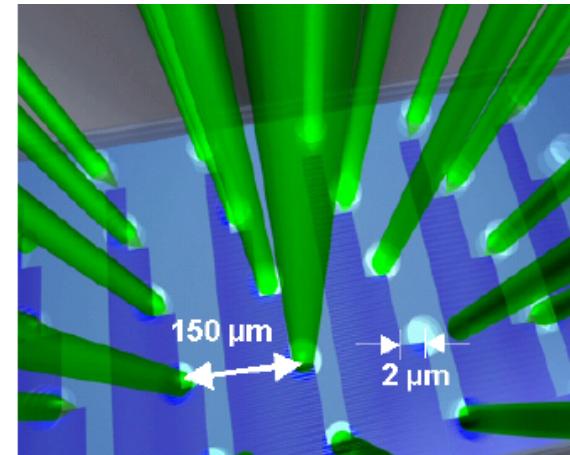
[Courtesy E-beam Initiative]

Multiple E-Beam Lithography

- Massively-Parallel e-beam writing
 - Each stripe has width of 50~200 microns
 - Stitching region has a width around 15nm [Berg+, SPIE'11]
 - Field stitching



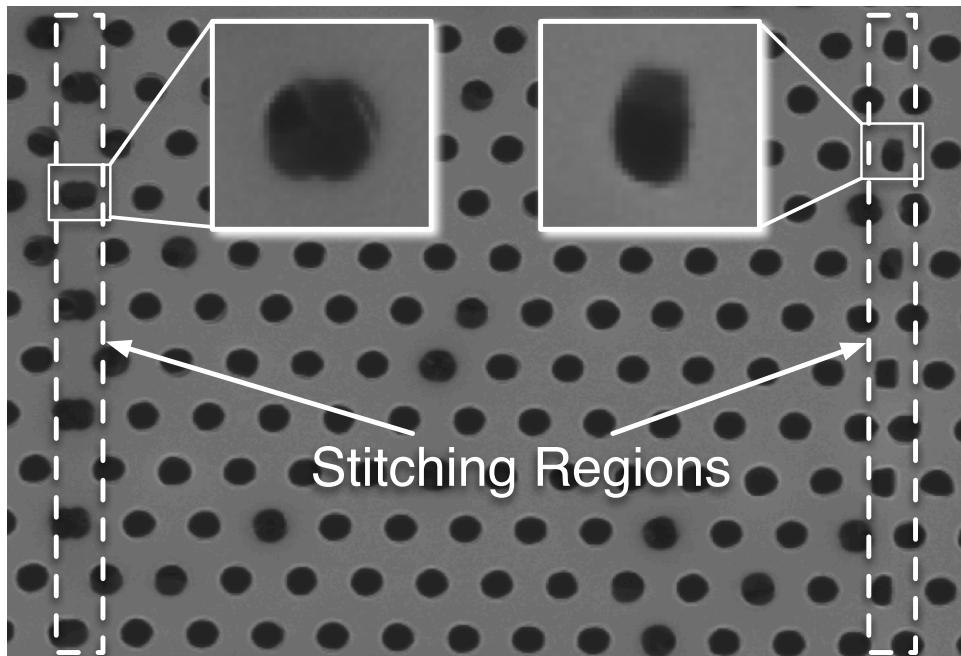
[Fang+, DAC'13]



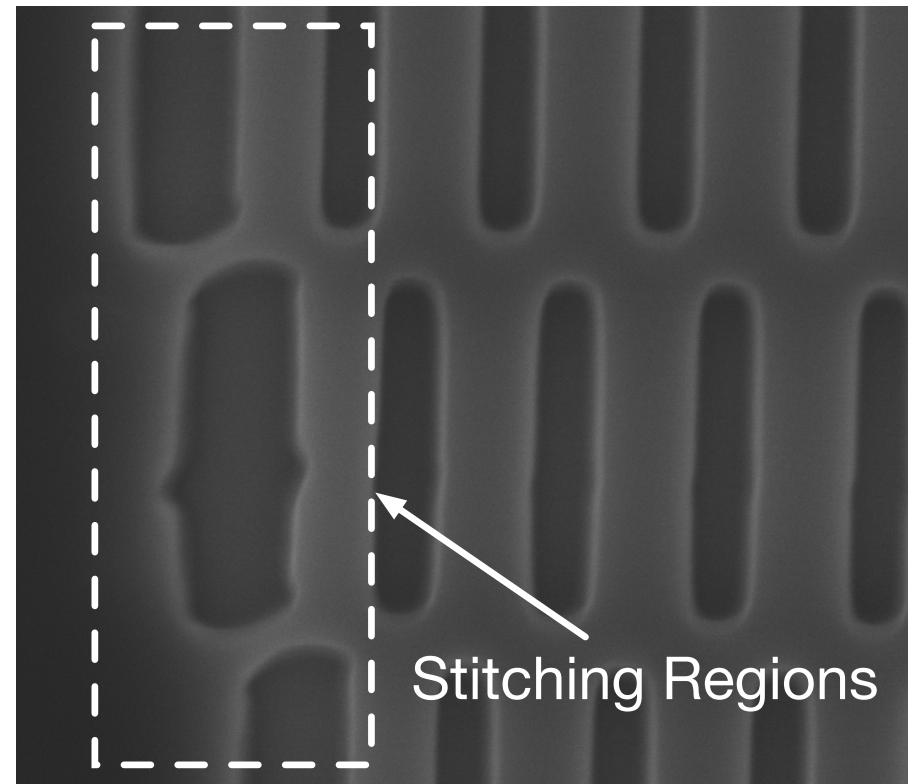
MAPPER Lithography System

Field Stitching

- SEM figures showing stitches at boundaries of beam stripes



Holes



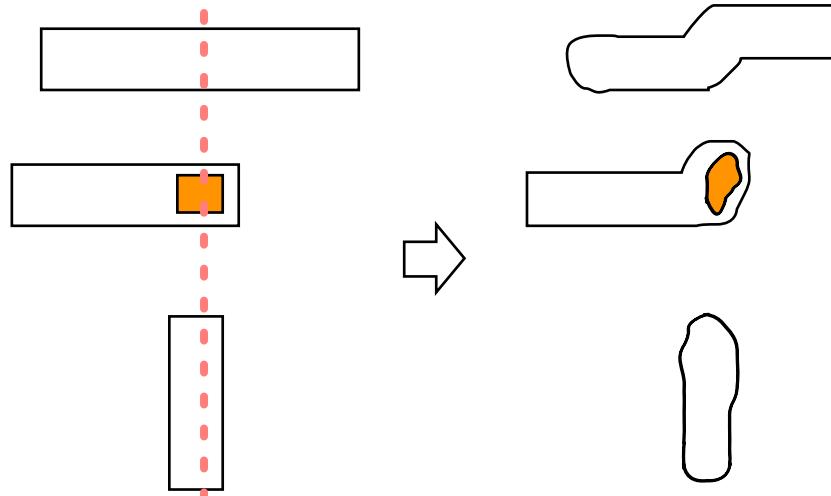
Lines

Previous Work

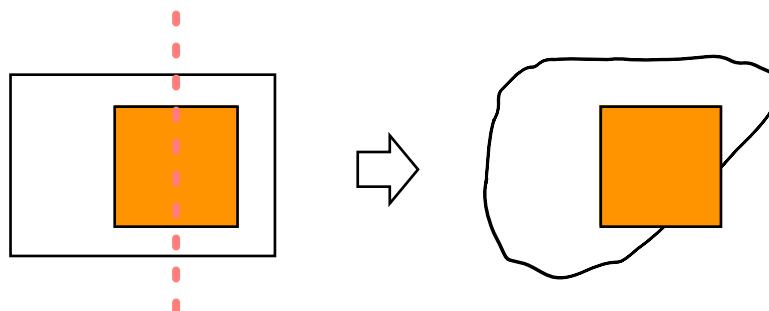
- Stitch aware routing for MEBL
 - [Fang+, **DAC'13**], [Liu+, **TCAD'15**]
- TPL aware placement
 - [Yu+, **TCAD'15**], [Kuang+, **TVLSI'15**], [Chien+, **TCAD'15**]
 - [Tian+, **ICCAD'14**], [Lin+, **ISPD'15**]
 - TPL applies **different** constraint to placement from MEBL
- No placement algorithm addressing MEBL stitch constraint yet

Stitch Errors

- Defects on vias and vertical wires

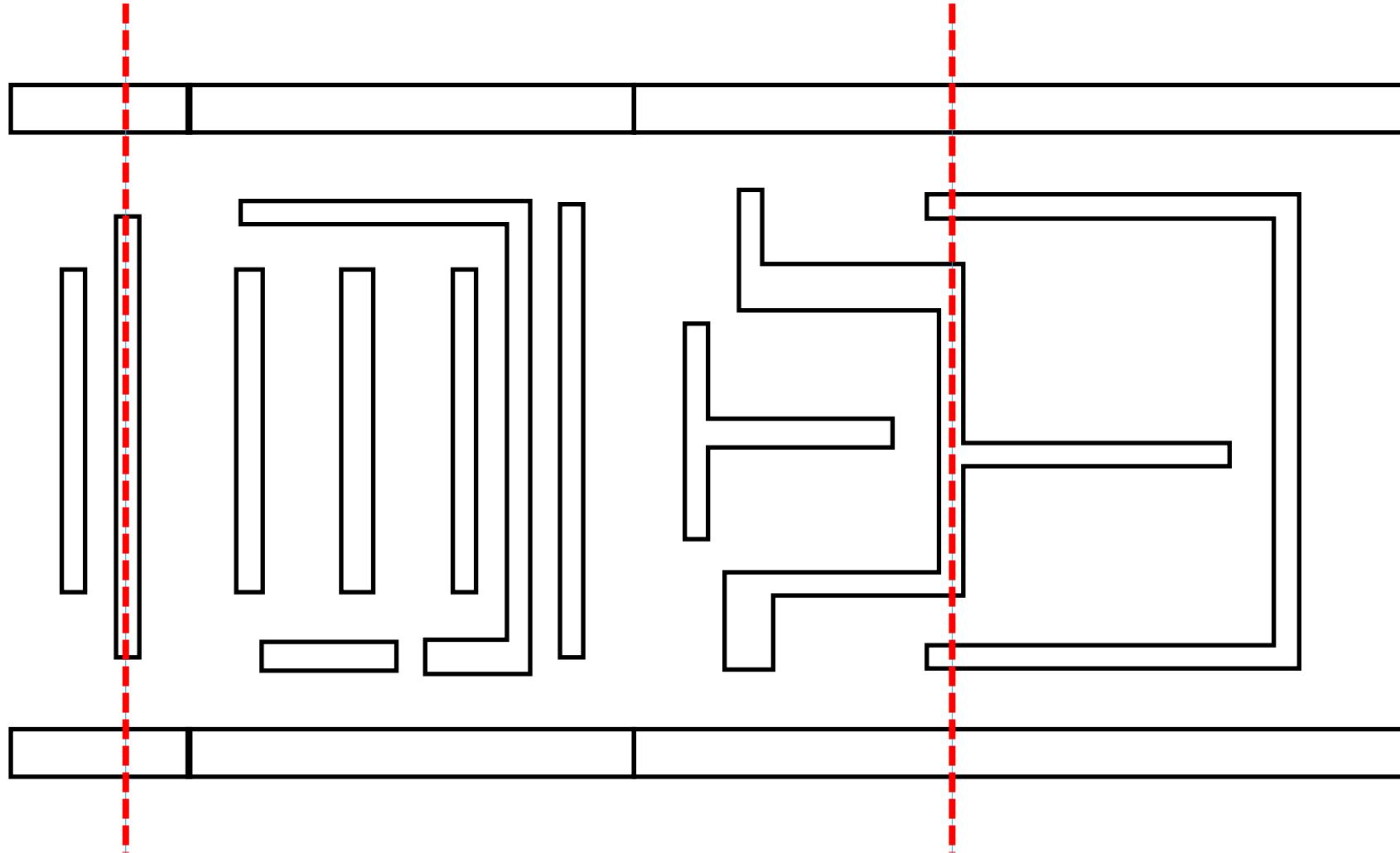


- Defects on short polygons



[Fang+, DAC2013]

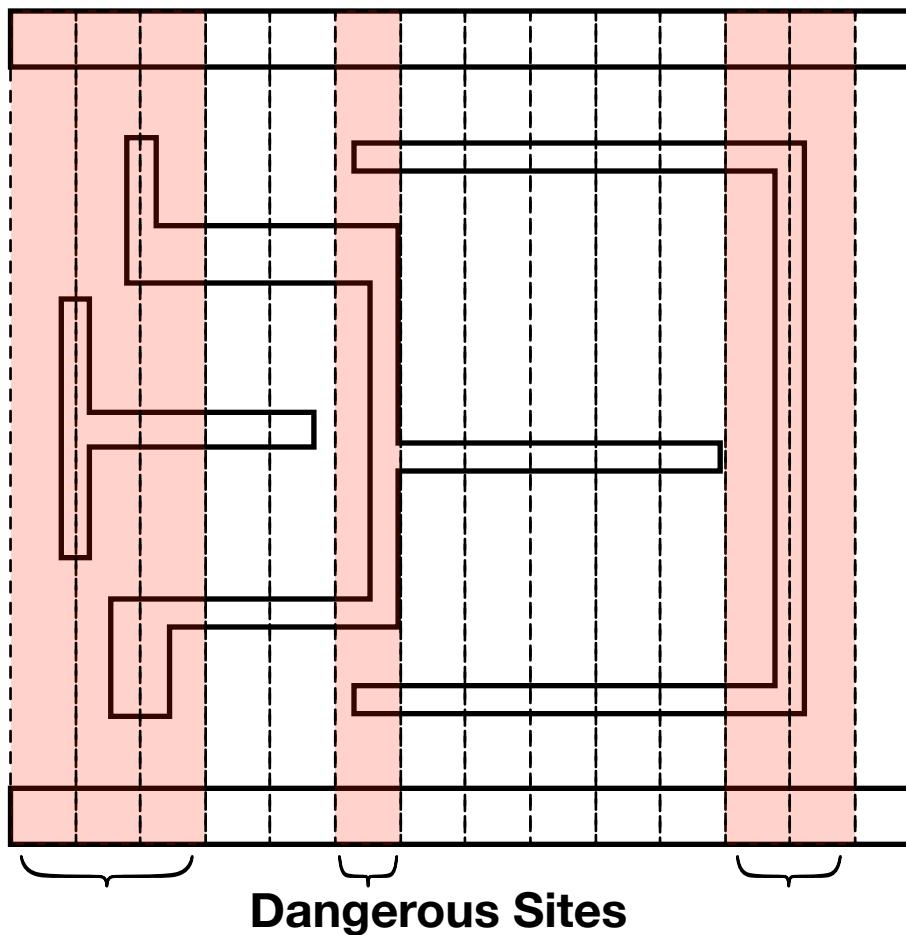
Stitch Errors within Standard Cell



Resolve stitch errors by proper placement

Dangerous Site Representation

- A cell is divided into sites (poly pitch)
- Sites that contain susceptible segments are marked as “dangerous sites”



Problem Formulation



- Input
 - Initial placement
 - Dangerous site information for each standard cell (precomputed)
- Output
 - New placement with optimized wirelength and minimum stitch errors
 - MEBL friendliness

Single Row Placement & Previous Work

- Given a set of ordered cells c_1, c_2, \dots, c_n , place cells horizontally to minimize objectives such as wirelength or movement
- Previous work on single row algorithm
 - Conventional objectives
 - [Brenner+, DATE'00], [Kahng+, GLSVLSI'04], Abacus [Spindler+, ISPD'08], [Taghavi+, ICCAD'10]
 - TPL awareness
 - [Yu+, ICCAD'13]: $O(mnK)$
 - [Kuang+, ICCAD'14]

Note: $\tau = 10, \phi = 1, v = 1$ in the experiment

Single Row Placement

- Given a set of ordered cells c_1, c_2, \dots, c_n , with maximum cell displacement M
 - Minimize wirelength and stitch errors
 - An algorithm supports a cost function generalizes wirelength, movement and stitch errors

$$cost_i(p_i) = \tau \cdot WL(p_i) + \phi \cdot MOV(p_i) + \nu \cdot SP(p_i)$$

Movement

Wirelength cost

Stitch error penalty

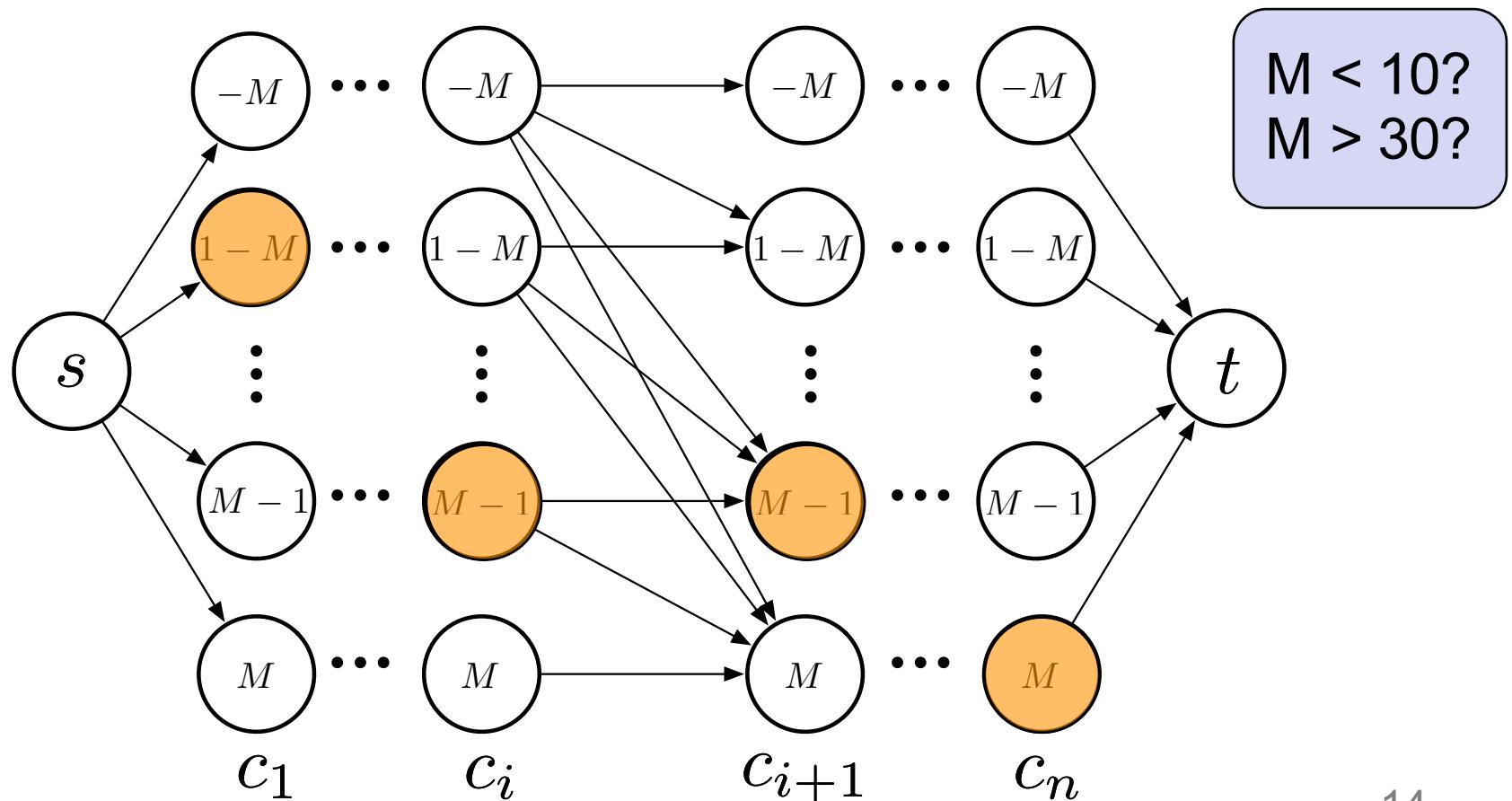
$$SP(p_i) = \begin{cases} 0, & \text{no stitch error} \\ \text{large number}, & \text{stitch error} \end{cases}$$

Note: $\tau = 10, \phi = 1, \nu = 1$ in the experiment

Single Row Placement



- Given a set of ordered cells c_1, c_2, \dots, c_n , with maximum cell displacement M
 - Shortest path solved by dynamic programming
 - $O(nM^2)$



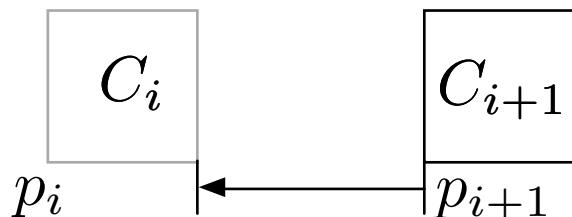
Speedup with Pruning Techniques



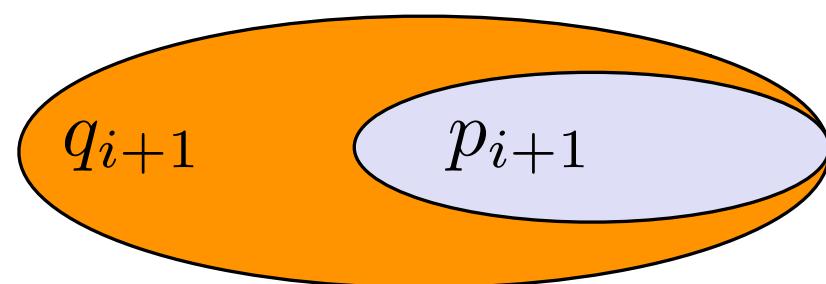
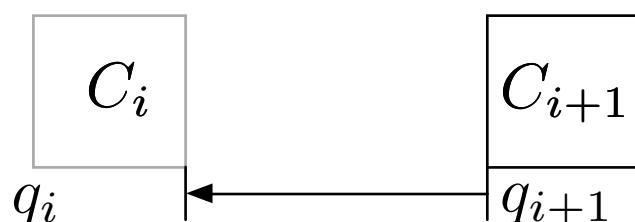
- Pruning technique 1

- Let $t_i(p_i)$ denote the cost of placement solution from c_1 to c_i in which c_i is placed at p_i
- Comparing two solutions $\alpha_i(p_i)$ and $\alpha_i(q_i)$, if $t_i(p_i) \geq t_i(q_i)$ and $p_i \geq q_i$, then $\alpha_i(p_i)$ is inferior to $\alpha_i(q_i)$.
- Prune inferior solutions

Solution $\alpha_i(p_i)$



Solution $\alpha_i(q_i)$



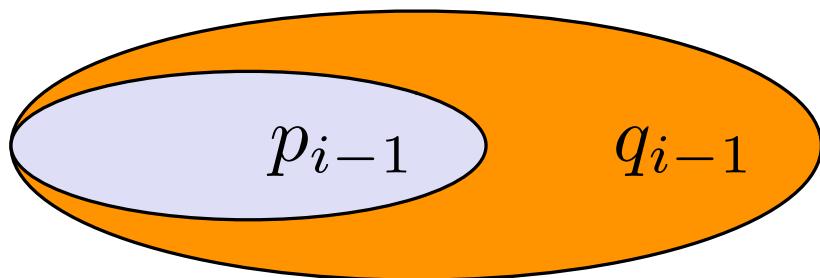
Value sets of p_{i+1} and q_{i+1}

Speedup with Pruning Techniques



- Pruning technique 2

- Let p_{i-1}^* be the optimal position of cell c_{i-1} when cell c_i is placed at p_i
- Let q_{i-1}^* be the optimal position of cell c_{i-1} when cell c_i is placed at q_i
- If $q_i \geq p_i$, then $q_{i-1}^* \geq p_{i-1}^*$
- Reduce searching ranges

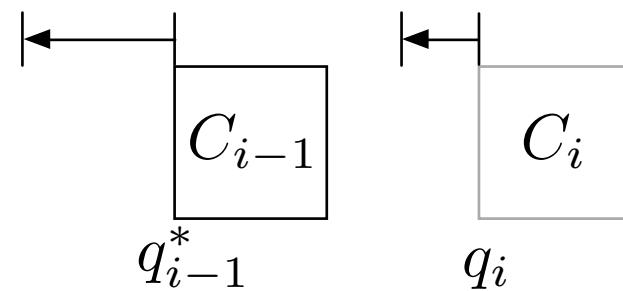


Value sets of p_{i-1} and q_{i-1}

Solution $\alpha_i(p_i)$



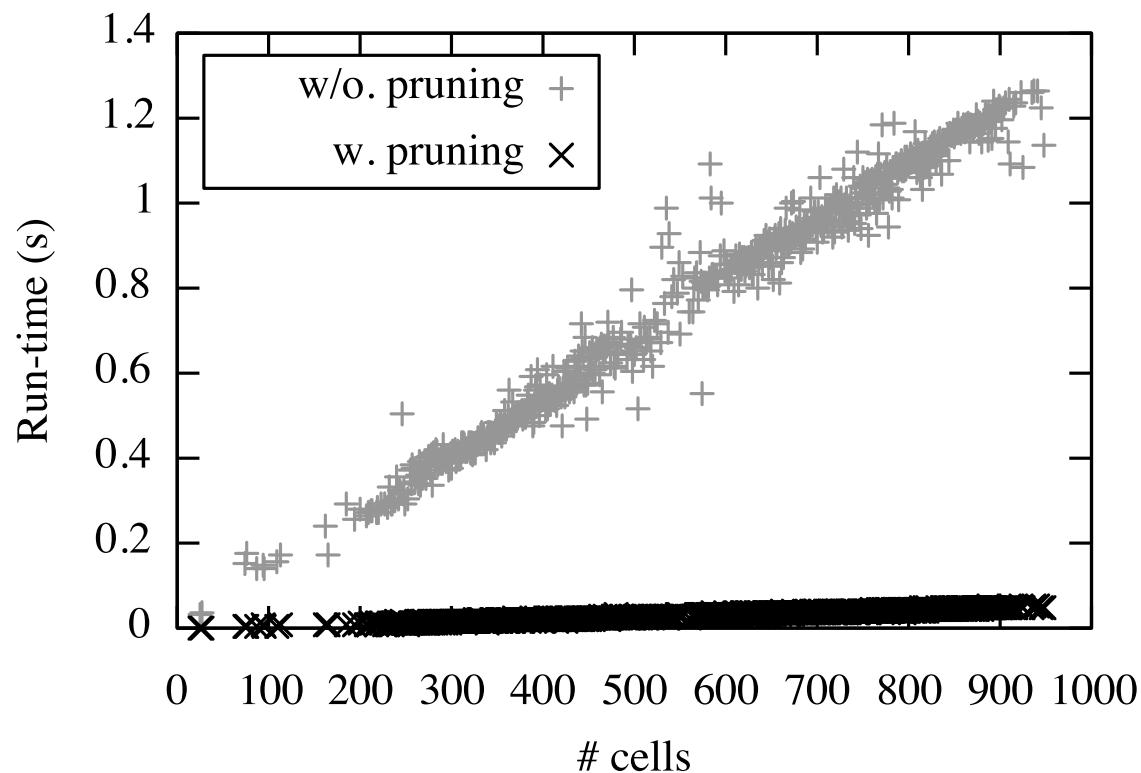
Solution $\alpha_i(q_i)$



Effectiveness of Speedup Techniques

- **O(nM) complexity**

- Requirements: $cost_i(p_i)$ only depends on p_i
- 30x speedup
- Keep **optimality**



Resolve Stitch Errors in Dense Regions

- Global swap to smooth out density

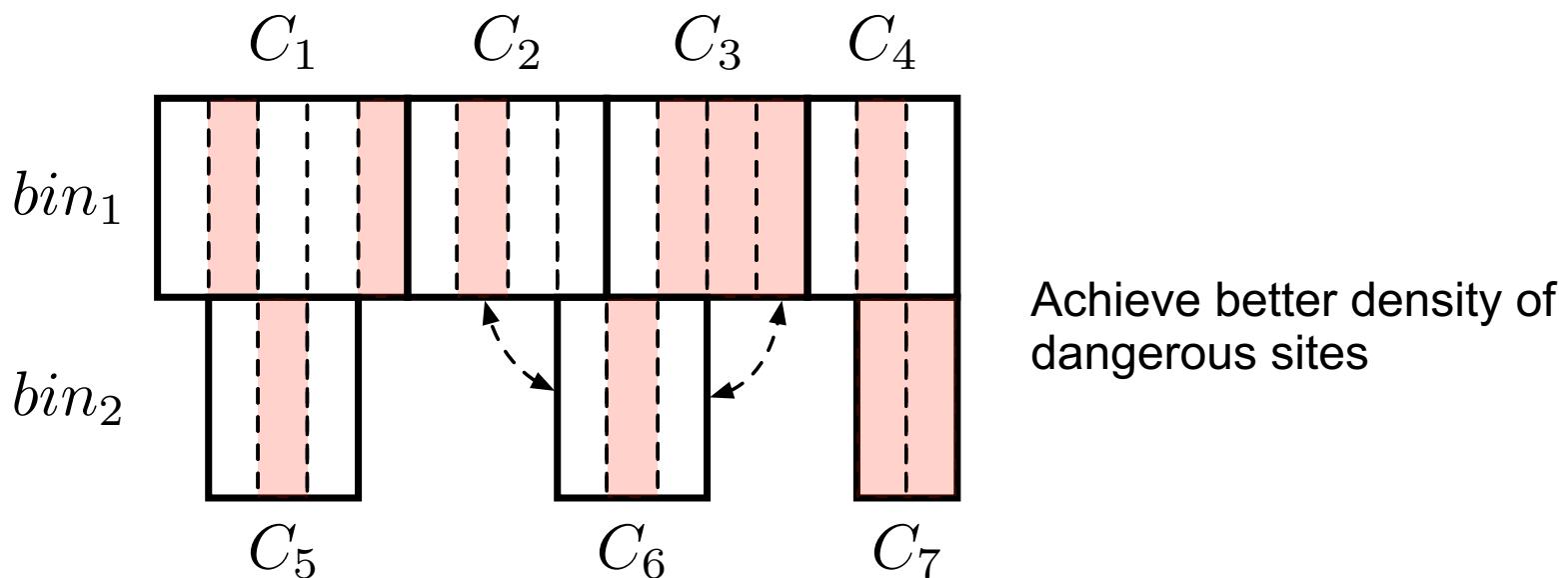
- $score(c_i, c_j) = \Delta sHPWL - \lambda \cdot P_{ds} - \mu \cdot P_{ov}$

sHPWL change

Overlap penalty

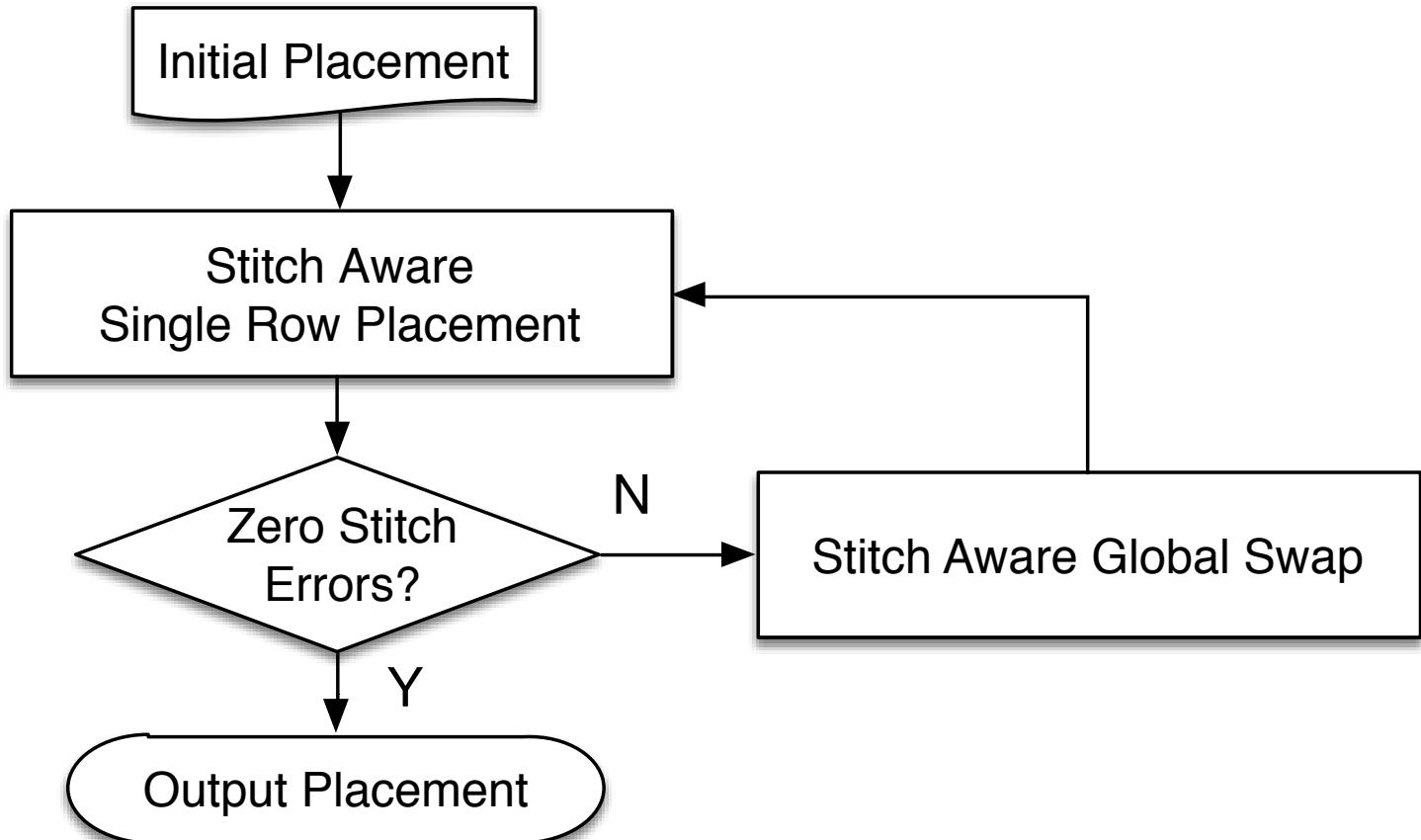
Normalized penalty of dangerous site density

$P_{ds} = \max(0, |D'_{ds}(i) - D'_{ds}(j)| - |D_{ds}(i) - D_{ds}(j)|) \cdot A_b$
 $D_{ds}(i)$: the density of dangerous sites in bin B_i before swap
 $D'_{ds}(i)$: the density of dangerous sites in bin B_i after swap
 A_b : bin area



Note: $sHPWL = HPWL \times (1 + \alpha \times P_{ABU})$ from ICCAD 2013 Contest

Overall Flow



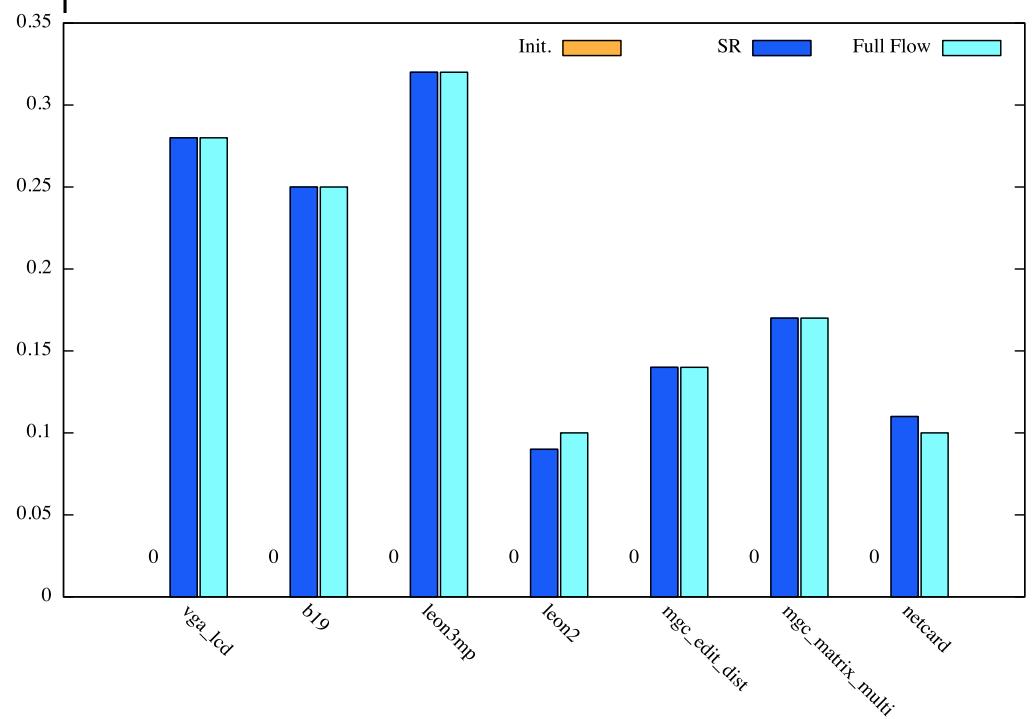
Experimental Environment Setup

- Implemented in C++
- 8-Core 3.4GHz Linux server with 32GB RAM
- ICCAD 2014 contest benchmark
 - Mapped to Nangate 15nm Standard Cell Library
 - Legalized with RippleDP [Chow+, ISPD'14]

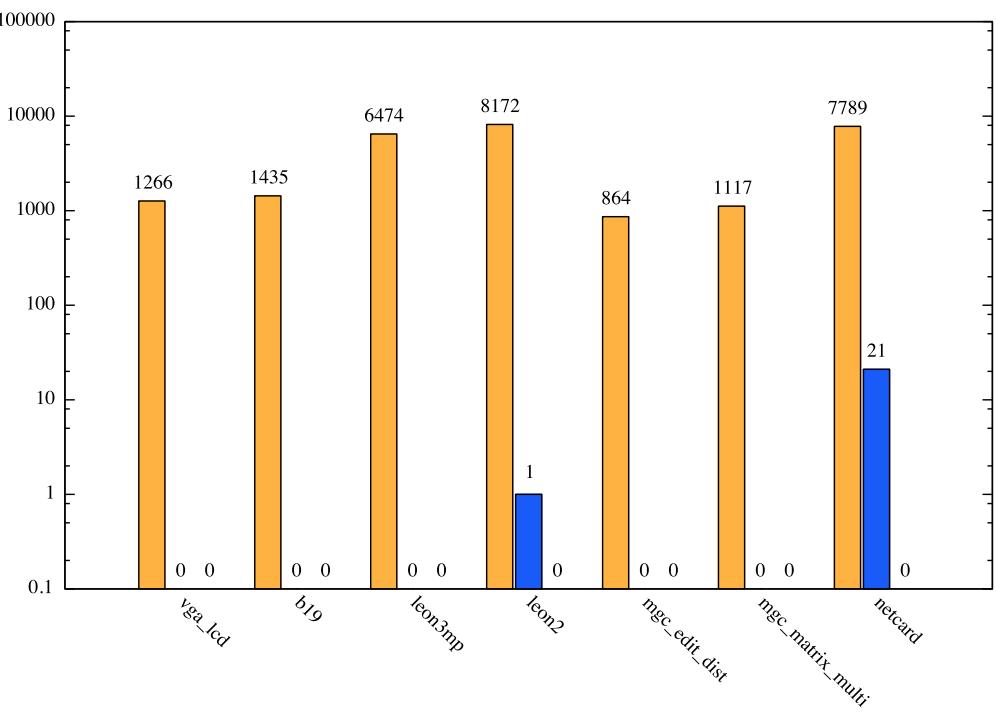
Design	#cells	#nets	#blockages
vga_lcd	165K	165K	0
b19	219K	219K	0
leon3mp	649K	649K	0
leon2	794K	795K	0
mgc_edit_dist	131K	133K	13
mgc_matrix_mult	155K	159K	16
netcard	959K	961K	12

Experimental Results

Wirelength Improvement %



Final Stitch Errors



Init.: initial input placement

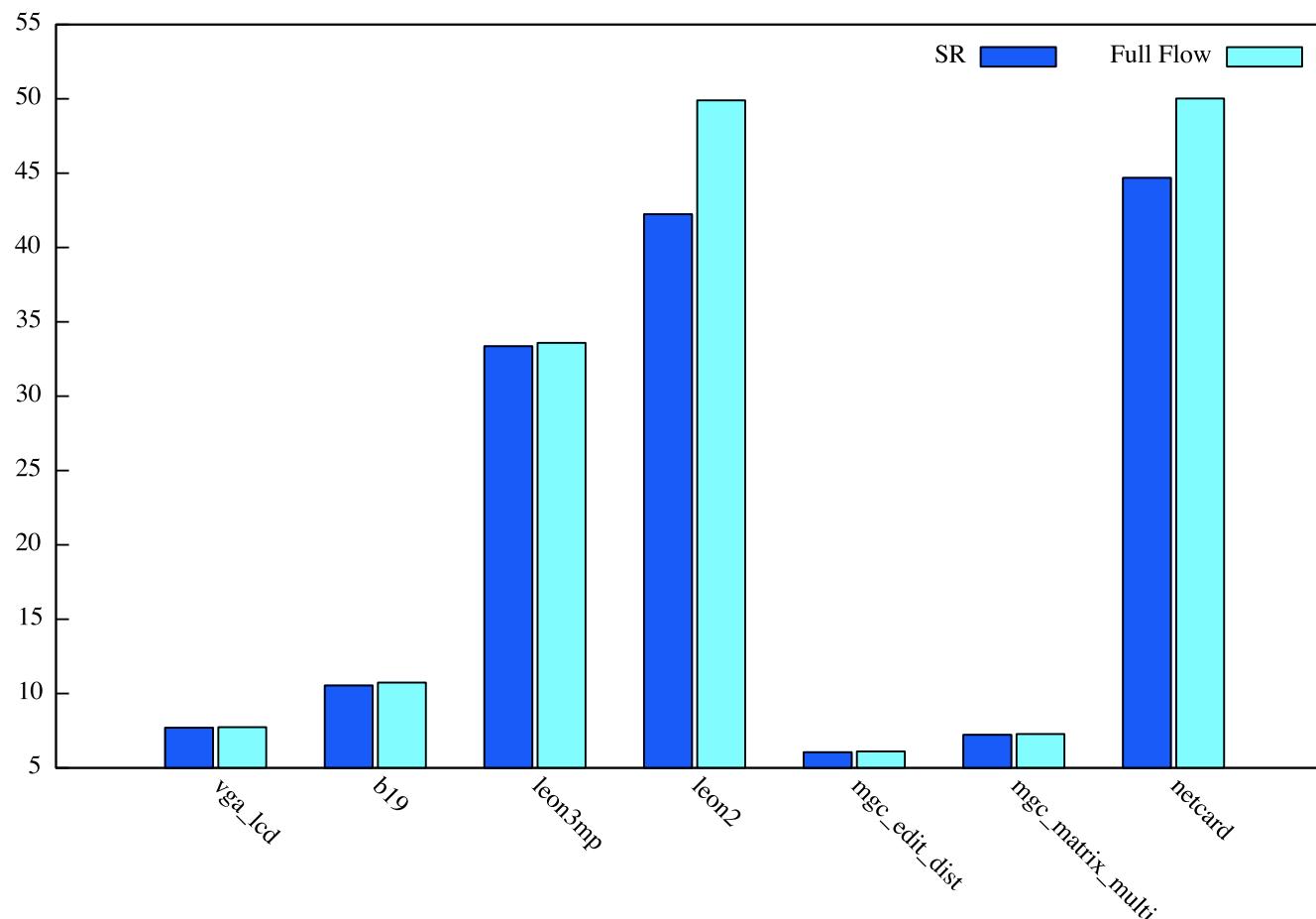
SR: single row algorithm only

Full Flow: apply full flow including single row algorithm and global swap

Runtime Comparison

- Full flow is slightly slower than SR
 - Only apply to regions still containing stitch errors

Runtime (s)



Conclusion

- Methodology to handle e-beam stitch errors during detailed placement stage
- A **linear** time single row algorithm with highly-adaptable objective functions
- Can be utilized in existing CAD tool on optimizing: **Wire-length**; **Routability**; **Congestion**, etc.
- Future work
 - Consider interaction between placement and routing for EBL friendliness



Thanks